

Product data sheet

1. Product profile

1.1 General description

Hybrid high dynamic range amplifier module operating at a supply voltage of 24 V (DC) in a SOT115J package. The module consists of two cascaded stages both in cascode configuration.

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

1.2 Features

- Excellent linearity
- Extremely low noise
- High gain
- Excellent return loss properties

1.3 Applications

Single module line extender in CATV systems operating in the 40 MHz to 750 MHz frequency range.

1.4 Quick reference data

Table 1:	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G _p	power gain	f = 50 MHz	33.2	-	35.2	dB
		f = 750 MHz	33.5	-	-	dB
I _{tot}	total current consumption	V _B = 24 V	[1] 285	-	325	mA

[1] The module normally operates at $V_B = 24$ V, but is able to withstand supply transients up to 30 V.



BGE788C

750 MHz, 34 dB gain push-pull amplifier

2. Pinning information

Table 2:	Pinning	
Pin	Description	Simplified outline Symbol
1	input	
2	common	
3	common	
5	+V _B	
7	common	
8	common	sym09
9	output	

3. Ordering information

Table 3: Ordering information					
Type number	Package				
	Name	Description	Version		
BGE788C	-	rectangular single-ended package; aluminium flange; 2 vertical mounting holes; $2 \times 6-32$ UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads	SOT115J		

4. Limiting values

Table 4: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
VB	supply voltage		-	25	V
Vi	RF input voltage		-	55	dBmV
T _{stg}	storage temperature		-40	+100	°C
T _{mb}	mounting base temperature		-20	+100	°C

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5. Characteristics

Table 5: Characteristics

Bandwidth 40 MHz to 750 MHz; $V_B = 24$ V; $T_{mb} = 30 \circ C$; $Z_S = Z_L = 75 \Omega$.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G _p	power gain	f = 50 MHz	33.2	-	35.2	dB
		f = 750 MHz	33.5	-	-	dB
SL	slope cable equivalent	f = 40 MHz to 750 MHz	0.3	-	2.3	dB
FL	flatness of frequency response	f = 40 MHz to 750 MHz	-	-	±0.6	dB
S ₁₁ ²	input return losses	f = 40 MHz to 320 MHz	16	-	-	dB
		f = 320 MHz to 640 MHz	15	-	-	dB
		f = 640 MHz to 750 MHz	14	-	-	dB
s ₂₂ ²	output return losses	f = 40 MHz to 320 MHz	16	-	-	dB
		f = 320 MHz to 640 MHz	15	-	-	dB
		f = 640 MHz to 750 MHz	14	-	-	dB
φ _{s21}	phase response	f = 50 MHz	135	-	225	deg
СТВ	composite triple beat	110 channels flat; V _o = 44 dBmV; measured at 745.25 MHz	-	-	-49	dB
CSO	composite second order distortion	110 channels flat; V _o = 44 dBmV; measured at 746.5 MHz	-	-	-52	dB
NF	noise figure	f = 50 MHz	-	-	8	dB
I _{tot}	total current consumption		[1] 285	-	325	mA

[1] The module normally operates at $V_B = 24$ V, but is able to withstand supply transients up to 30 V.

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6. Package outline

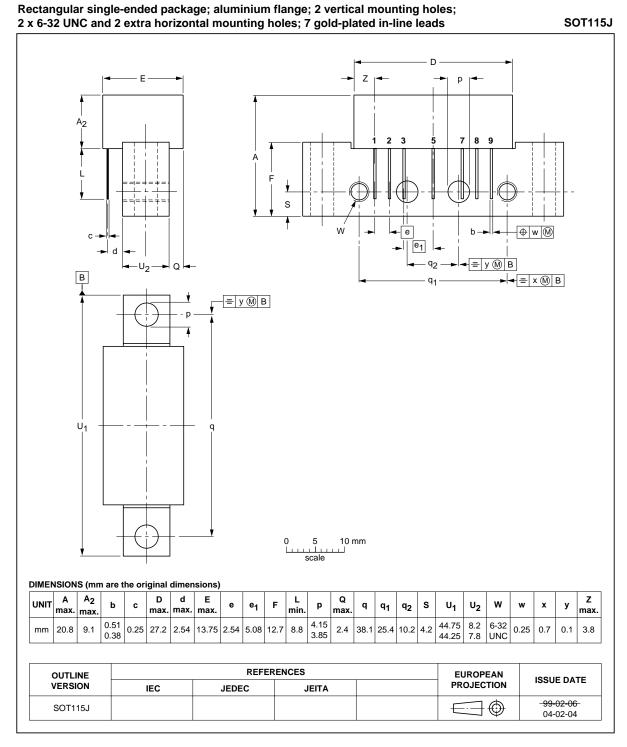


Fig 1. Package outline SOT115J

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7. Revision history

Table 6: Revision hi	Revision history				
Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
BGE788C_1	20050401	Product data sheet	-	9397 750 14607	-

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8. Data sheet status

Level	Data sheet status [1]	Product status [2] [3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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